

Optical Node RF Amplifier 50 - 1000 MHz

Rev. V1

Features

- -6 dBm to +2 dBm Optical Input Range
- Low Equivalent Input Noise (EIN): 3.2 pA/rtHz
- Single +5 V Bias
- 29 dB Gain at 55 MHz; 34 dB Gain at 1000 MHz
- 27 dB Gain Control Range
- +24 dBmV/ch Output at 550 MHz
- Lead-Free 4 mm PQFN-24LD Plastic Package
- Halogen-Free "Green" Mold Compound
- RoHS* Compliant and 260°C Reflow Compatible

Description

The MAAM-010333 provides high gain, low noise and low distortion amplification for optical node applications.

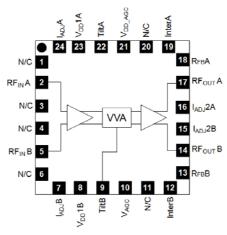
The MAAM-010333 is fabricated using M/A-COM Technology Solutions' low noise GaAs pHEMT technology in a lead-free 4 mm 24-lead package. The amplifier requires a minimal number of off-chip components resulting in a highly integrated low cost solution.

Ordering Information ^{1,2}

Part Number	Package
MAAM-010333-TR1000	1000 Piece Reel
MAAM-010333-TR3000	3000 Piece Reel
MAAM-010333-001SMB	Sample Test Board

- 1. Reference Application Note M513 for reel size information.
- 2. All sample boards include 5 loose parts. Sample board is supplied with mounted photodiode.
- * Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

Functional Schematic



Pin Configuration ³

Pin Configuration				
Pin No.	Pin Name	Description		
1	N/C	No Connection		
2	RF _{IN} A	RF Input A		
3	N/C	No Connection		
4	N/C	No Connection		
5	RF _{IN} B	RF Input B		
6	N/C	No Connection		
7	$I_{ADJ}B$	Current Adjust		
8	V _{DD} 1B	+ 5V Bias Voltage		
9	TiltB	Tilt Connection		
10	V_{AGC}	AGC Control Voltage: 0V to 3V		
11	N/C	No Connection		
12	InterB	Interstage Pin		
13	R _{FB} B	Feedback Resistor		
14	RF _{OUT} B	RF Output B		
15	I _{ADJ} 2B	Current Adjust		
16	I _{ADJ} 2A	Current Adjust		
17	RF _{OUT} A	RF Output A		
18	$R_{FB}B$	Feedback Resistor		
19	InterA	Interstage Pin		
20	N/C	No Connection		
21	V_{DD_AGC}	+ 5V AGC Bias Voltage		
22	TiltA	Tilt Connection		
23	$V_{DD1}A$	+ 5V Bias Voltage		
24	I _{ADJ} 1	Current Adjust		
25	Paddle	RF & DC Ground		

3. The exposed pad centered on the package bottom must be connected to RF and DC ground.

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Electrical Specifications⁴: $V_{DD} = +5$ Volts, $T_A = 25$ °C, $Z_0 = 75$ Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Trans-Impedance Gain ^{5,6}	50 MHz 870 MHZ 1 GHz	dB	26.5 31.0 31.5	29.0 33.0 34.0	30.5 35.0 35.5
Gain Tilt ⁷	$V_{AGC} = +3 V$ $V_{AGC} = 0 V$	dB	-	5 7	-
Gain Flatness 8	V _{AGC} : 0 to 3 V	dB		0.7	
Gain Control Range	50 MHz 870 MHZ 1 GHz	dB	25.5 23.0 24.0	29.0 26.0 27.0	32.0 29.0 30.0
AGC Control Voltage Range	50 MHz - 1 GHz	V	0	-	+3
EIN ⁶	50 MHz - 1 GHz	pA/rtHz	1	3.2	-
Output Return Loss	50 MHz - 1 GHz	dB	-	18	-
CTB ⁹	79 channels	dBc	-	-68	-
CSO ⁹	79 channels	dBc	-	-65	-
Current	$V_{DD} = +5 V$	mA	225	260	295

- 4. Performance is specified using JDSU Photodiode EPM-745 or equivalent (EPM705) and output balun # MABA-009210-CT1760.
- 5. Gain = $20*log(Z_T/75)$, where Z_T = Transconductance (Ω)
- 6. Specified at maximum gain (V_{AGC} = +3.0 V)
- 7. Positive gain slope from 50 MHz to 1 GHz (tilt of best fit straight line from 50 MHz to 1 GHz)
- 8. Flatness defined as peak-peak deviation from best fit straight line.
- 9. Optical Input Power Range: -6 dBm to +2 dBm; 79 channels

OMI = 3.5%; Pout = +24 dBmV/ch at 550 MHz

 P_{OUT} = +22.5 dBmV/ch at 55 MHz; +24 dBmV/ch at 550 MHz

Absolute Maximum Ratings 10,11,12

Parameter	Absolute Maximum	
Input Power	+3 dBm Optical	
Operating Voltage	+15 volts	
AGC Voltage	+5 volts	
Operating Temperature	-40°C to +85°C	
Junction Temperature ¹³	+150°C	
Storage Temperature	-65°C to +150°C	

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM Technology Solutions does not recommend sustained operation near these survivability limits.
- 12. Operating at nominal conditions with $T_J \le +150$ °C will ensure MTTF > 1 x 10^6 hours.
- 13. Junction Temperature $(T_J) = T_C + \Theta jc * ((V * I) (P_{OUT} P_{IN}))$ Typical thermal resistance $(\Theta jc) = 19^{\circ}$ C/W.

a) For $T_C = 25^{\circ}C$,

 T_J = 53 °C @ 5 V, 295 mA

b) For $T_C = 85^{\circ}C$,

T_J = 112 °C @ 5 V, 295 mA

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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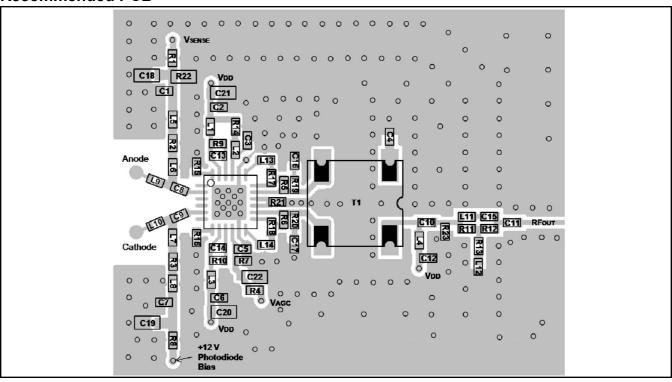
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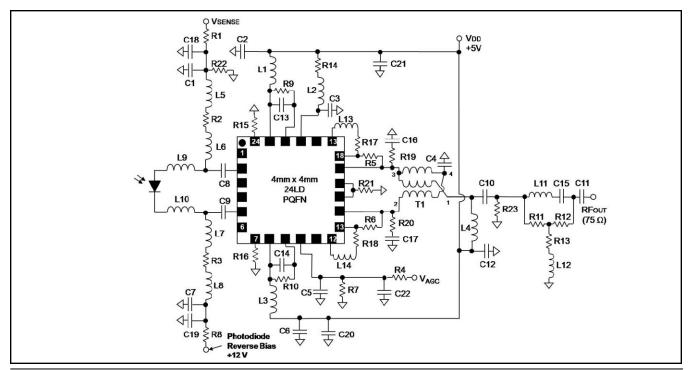
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Recommended PCB



Schematic Including Off-Chip Components



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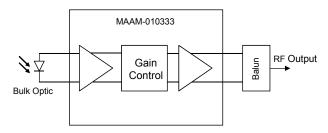
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Parts List

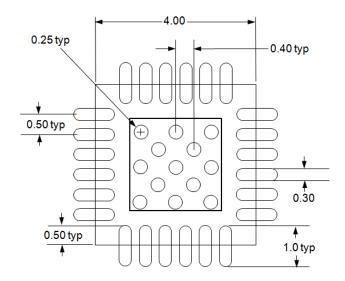
Component	Value	Case Style
L1 - L8 ¹⁴	Ferrite Bead	0402
L9 - L10	12 nH w/w	0402
L11	8.2 nH	0402
L12	33 nH	0402
L13 - L14	10 nH	0402
C1 - C12	10 nF	0402
C13 - C14	2.7 pF	0402
C15	3.0 pF	0402
C16 - C17	2.0 pF	0402
C18 - C22	1.0 µF	0603
R1 - R4	1 kΩ	0402
R5 - R7	680 Ω	0402
R8	200 Ω	0402
R9 - R10	120 Ω	0402
R11 - R12	39 Ω	0402
R13	82 Ω	0402
R14	180 Ω	0402
R15 - R16	12 Ω	0402
R17 - R18	47 Ω	0402
R19 - R20	62 Ω	0402
R21	6.2 Ω	0402
R22	1 kΩ	0603
R23	470 Ω	0402
T1 ¹⁵	1:1 Balun	SM-118A

14. Ferrite Bead from Murata, part number BLM15HD182SN 15. M/A-COM Technology Solutions MABA-009210-CT1760 1:1 T_X Line Balun

Application Schematic



PCB Land Pattern



All dimension are in mm

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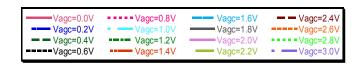
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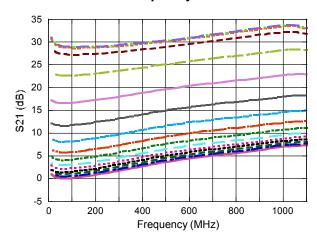
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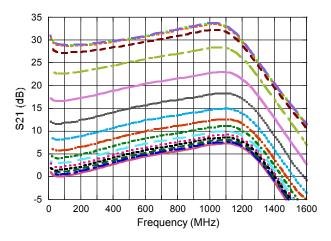
Typical Performance Curves: +25°C, VAGC = 0V to 3V in 0.2 V Steps



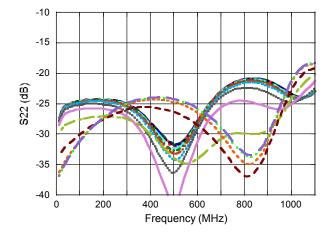
Receiver Gain vs. Frequency to 1.1 GHz



Receiver Gain vs. Frequency to 1.6 GHz



Output Return Loss vs. Frequency



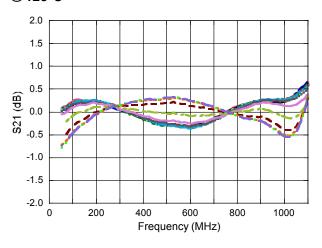


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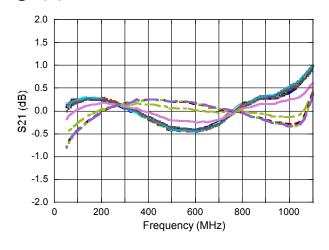
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Typical Performance Curves: VAGC = 0V to 3V in 0.2 V Steps

Gain Flatness Deviation From Best Fit Line @ +25°C

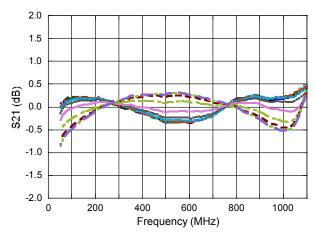


Gain Flatness Deviation From Best Fit Line @ -40°C



Gain Flatness Deviation From Best Fit Line

@ +85°C



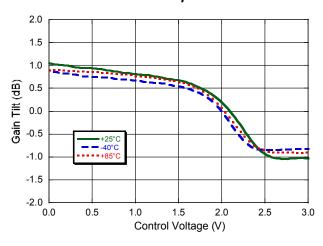


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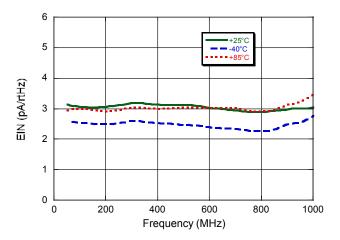
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Typical Performance Curves

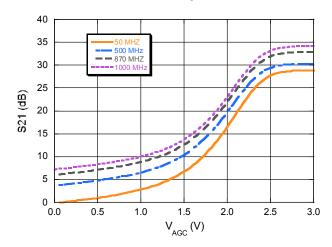
Gain Tilt Deviation from Average Tilt VAGC: 0V to 3V in 0.2 V Steps



Equivalent Input Noise @ Max Gain VAGC = 3V



Receiver Gain vs. VAGC VAGC = 0V to 3V in 0.2V Steps



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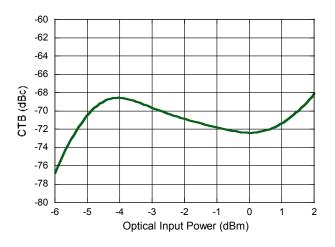
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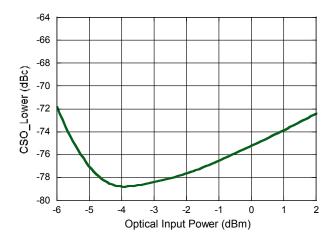
Typical Performance Curves:

79 Channels; NTSC Frequency Plan Pout = +22.5 dBmV/ch @ 55 MHz; +24 dBmV @ 550 MHz

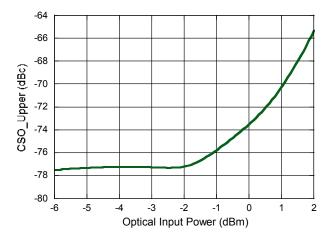
CTB vs. Optical Input Power



CSO_Lower vs. Optical Input Power



CSO_Upper vs. Optical Input Power



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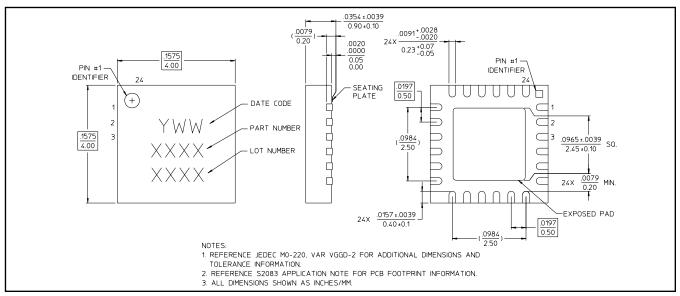
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Lead Free 4 mm 24-lead PQFN[†]



[†] Reference Application Note 2083 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements. Plating is 100% matte tin over copper.